

AMENDMENTS TO THE CLAIMS:

1-10. (Canceled)

11. (New) A charge pump-type booster circuit, comprising:

a pair of input terminals for providing an input voltage;

a charge capacitor;

a first pair of switches capable of alternatively assuming a first condition, coupling said charge capacitor across said pair of input terminals to charge said charge capacitor to a voltage level substantially equal to the voltage level of the input voltage, and a second condition decoupling said charge capacitor from across said input terminals;

a first output capacitor;

a second pair of switches capable of assuming a first condition, coupling said first output capacitor across a first serial combination, comprising said input terminals and said charge capacitor, to charge said first output capacitor to a voltage level substantially twice the voltage level of the input voltage, and a second condition, decoupling said first output capacitor from said first serial combination;

a second output capacitor; and

a third pair of switches capable of assuming a first condition, coupling said second output capacitor across a second serial combination, comprising said charge capacitor and said first output capacitor, to charge said second output capacitor to a voltage level substantially three times the voltage level of the input voltage, and a second condition, decoupling said second output capacitor from said second serial combination.

12. (New) The charge pump-type booster circuit as set forth in claim 11, further comprising a load connected in parallel with said first output capacitor.
13. (New) The charge pump-type booster circuit as set forth in claim 11, further comprising a load connected in parallel with said second output capacitor.
14. (New) The charge pump-type booster circuit as set forth in claim 11, further comprising a first load connected in parallel with said first output capacitor, and a second load connected in parallel with said second output capacitor.
15. (New) The charge pump-type booster circuit as set forth in claim 11, wherein each of said switches comprises a thin film transistor.
16. (New) A charge pump-type booster circuit, comprising:
 - a pair of input terminals for providing an input voltage;
 - a charge capacitor;
 - a pair of charge switches;
 - N output capacitors, identified in sequence as output capacitor number 1 to output capacitor number N; and
 - N pairs of boosting switches, wherein:
 - said pair of charge switches is capable of alternatively assuming a first condition,

coupling said charge capacitor across said pair of input terminals to charge said charge capacitor to a voltage level substantially equal to the voltage level of the input voltage, and a second condition decoupling said charge capacitor from across said input terminals,

a first one of said pairs of boosting switches is capable of alternatively assuming a first condition, coupling output capacitor number 1 across a first serial combination, comprising said input terminals and said charge capacitor, to charge output capacitor number 1 to a voltage level substantially twice the level of the input voltage, and a second condition decoupling output capacitor number 1 from said first serial combination,

a second one of said pairs of boosting switches is capable of alternatively assuming a first condition, coupling output capacitor number 2 across a second serial combination, comprising said charge capacitor and output capacitor number 1, to charge output capacitor number 2 to a voltage level substantially three times the input voltage level, and a second condition decoupling output capacitor number 2 from said second serial combination,

each of the remaining pairs of boosting switches is capable of assuming a first condition, coupling an associated output capacitor number n across an associated serial combination, comprising output capacitor number $(n-2)$ and output capacitor number $(n-1)$, to charge said output capacitor number n to a voltage level at least equal to $(n+1)$ times the input voltage level,

N is an integer greater than 2, and

n is an integer greater than 2 and less than or equal to N .

17. (New) The charge pump-type booster circuit as set forth in claim 16, further

comprising a load connected in parallel with one of said output capacitors.

18. (New) The charge pump-type booster circuit as set forth in claim 16, further comprising a plurality of loads, each load connected in parallel with one of said output capacitors.

19. (New) The charge pump-type booster circuit as set forth in claim 16, further comprising n loads, each load connected in parallel with one of said output capacitors.

20. (New) The charge pump-type booster circuit as set forth in claim 16, wherein each of said charge switches and each of said boosting switches comprise a thin film transistor.